



SES	C W . MAGNETRON	ISSUED
	FOR M ICROWAVE OVEN	2008 . 01 . 21 .

CUSTOMER SPECIFICATION OM75S

<PROHIBITION TO USE OZONE DEPLETING SUBSTANCES>

Prohibited substances :

CFC/Halon/Carbon tetrachloride/1,1,1-Trichloroethane(Methyl chloroform)

- ① This Product, Assembly, or Component does not contain any of the substances above mentioned.
- ② This Product, Assembly, or Component is not manufactured using any of the substances above mentioned.

COMPILED BY :					
APPROVED BY :					
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1. GENERAL

The SAMSUNG OM75S series is a continuous wave cooking magnetron with fixed frequency of 2465MHz and high efficiency. This magnetron is intended for use in microwave ovens with typical oven power 800~850 watts.

2. TYPICAL CHARACTERISTICS

2-1 ELECTRICAL

Power Supply.....	LC stabilized half wave doubler
Frequency.....	2465 MHz
Peak Anode Voltage.....	4.1 KV
Mean Anode Current.....	300 mA
Output Power (VSWR ≤ 1.1).....	910 W
Efficiency.....	71.0 %
Filament Voltage.....	3.3 V
Cold Filament Resistance.....	0.047 Ω
Pre-heating Time	0 sec

2-2 MECHANICAL

Mount Position (note 1).....	Any
R.F Coupler.....	WR 430 system
Magnetic System	Ferrite magnet packaged
Weight.....	0.83 Kg (1.8 lbs)
Dimensions.....	see outline drawing
Cooling Air Flow	800 l/m in
Pressure Drop.....	4.9 mm Aq
Cooling Direction.....	Transverse

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3. ABSOLUTE MAXIMUM RATINGS

	Min.	Max.
Filament Voltage.....	280 V	3.75 V
Mean Anode Current.....	-	350 mA
Peak Anode Current.....	-	1200 mA
Anode Temperature (note #2)..... (at the point indicated on the outline drawing)	-	300 °C
Load V.S.W.R (note #3).....	-	4
Storage Temperature.....	-35 °C	+60 °C
Filter Case Temperature.....	-	120 °C
Antenna Temperature	-	360 °C
Magnetron Output Power.....	860 W	960 w
Starting Time.....	-	3 sec

NOTES

#1. See 11/13 page.

#2. In an abnormal operation, the maximum allowable temperature for anode is 340°C , provided that dwell time of the maximum temperature does not exceed 2 hours per operation nor 25 hours in total.

#3. The bad condition in which instantaneous V.S.W.R is 4 through 10 may be allowed only if the dwell time in that is short.

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4. TEST SPECIFICATION

4-1. ELECTRICAL TEST

TERM	Test Cond.					Limits				
	Vf (V)	Va (kV)	Ia (mA)	VSWR	Notes	Min.	Mean	Max.	Unit	Notes
Cold Insulation Resistance	0	1kv dc	-	-	-	50M Ω	-	∞		
Breakdown Voltage	0	+10dc	-	-						#1
Cold start(Voltage transient)	33	-	300	≤ 1.1	#2			8	kV	#5
Frequency	33	-	300	≤ 1.1	#2	2455	2465	2475	MHz	
Peak Anode Voltage	33	-	300	≤ 1.1	#2	395	4.1	43	kV	
Efficiency	33	-	300	≤ 1.1	#2	700	-	-	%	
Mean Output Power(1)	33	4.1	300	≤ 1.1	#2	860	910	960	W	
Emission Stability(V/m)			300	≤ 1.1	#2			23	V	#3
Stability	33				#4	4			VSWR	#6
Pulling Figure	33		300	13				10	MHz	#6
Filament Current	33	-	-	-		85	105	125	A	
Sirk Phase (at L=4)	33	-	300	4		026	028	030	λ sh λ g	

4-2. VISUAL & MECHANICAL

1) Major Defects :

Any physical error, omission or dimensional deviation that affects the component function, fit or reliability.

2) Minor Defects :

Any physical error, omission or dimensional deviation that is purely aesthetic and does not affect function, fit or reliability.

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4-3. LABEL

Unless otherwise agreed with individual customers, a standard SAMSUNG label will be provided on the filter box of the tube.

4-4. DESIGN OR CONSTRUCTIONAL CHANGES :

SAMSUNG will notify the customer in writing of any major design or constructional changes which either change the performance of the magnetron or have an influence on the mechanical or appearance of the tubes.

Together with the notification sample, test data, and reason for modification will be sent to the customer for approval.

4-5. NOTES

#1. - If during the first snap-on there is evidence of a breakdown within 5 seconds of H.V. application, the test should be repeated once and there should be no indication of breakdown again.

(1 breakdown \leq 400 μ A , Series resistance 50K Ω)

#2. - For power supply an L.C., single phase half wave doubler should be used.

- The filament voltage should be measured at tube terminals.

- The combination of transformer and capacitor should be chosen such that for normal line voltage, I_a mean=300mA \pm 1% and I_a peak 1020 to 1050mA.

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- It is recommended to use a 10 - 12 KV avalanche diode as protection for capacitor and transformer.
- For wave guide configuration and power supply, see page 7 and 10.
- A water load of which the VSWR ≤ 1.1 over the frequency band 2425MHz up to 2475MHz should be used.
- Unless otherwise stated, limits apply for a tube within 15 seconds after application of voltage and at 25°C .
- Before testing, the tube should be "at room temperature" for at least four hours.
- During test, the magnetron should be cooled with 800 l/min of forced air.

#3. - After a minimum operation of 30 seconds under the specified condition, the filament voltage is gradually decreased. The V_{fm} is the lowest V_f value at which the tube is still oscillating in the π mode.

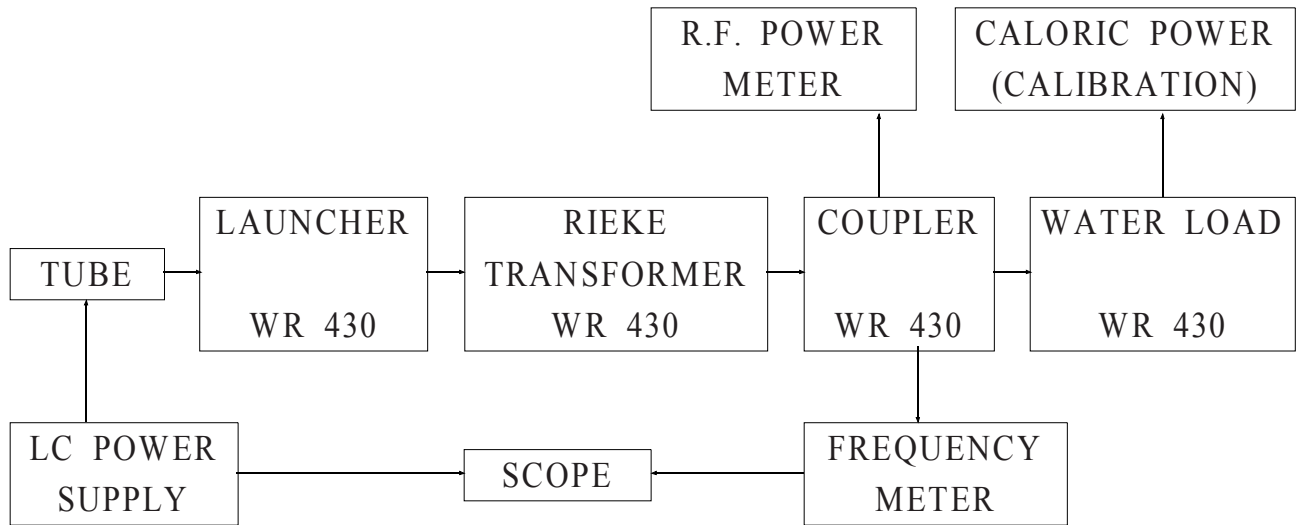
#4. - Starting with minimum operation of 30 seconds at nominal heater voltage and $I_a=300mA$ with VSWR ≤ 1.1 and at 2 λ g distance from the tube, the VSWR must be increased by means of the Rieke transformer while the phase must be varied in the sink area. The stability is the highest VSWR at which the tube is still oscillating in the correct π mode.

#5. - Transients are measured on a storage scope during the period 0.5 to 2 seconds after switching on the anode voltage and filament voltage simultaneously.

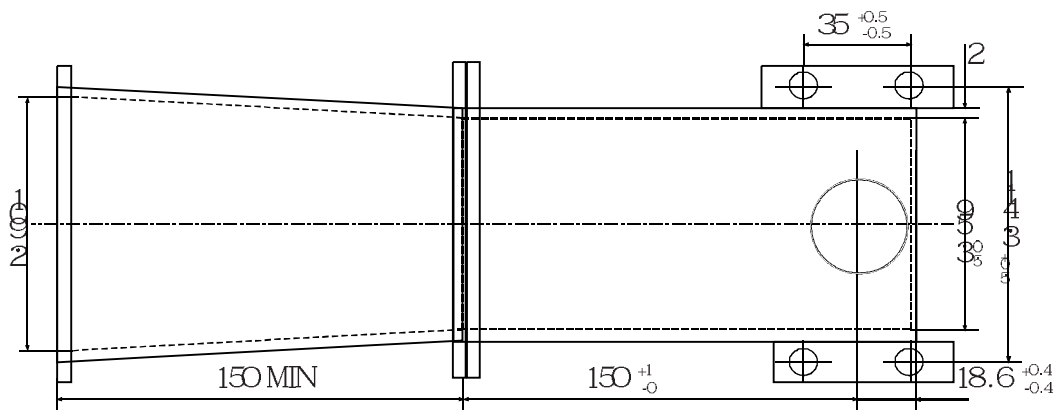
#6. - Design control tests only.

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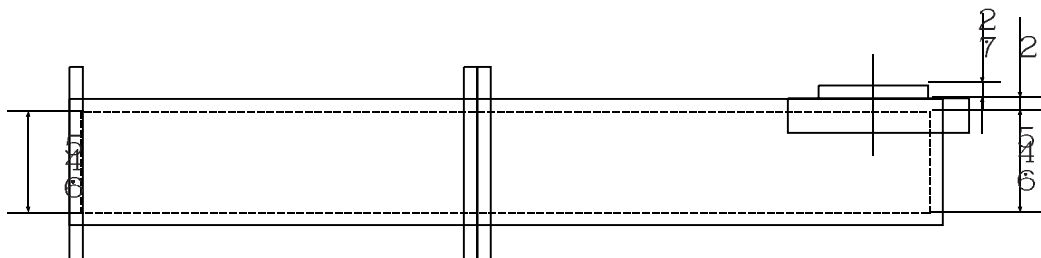
5. WAVEGUIDE CONFIGURATION



6. COUPLING SECTION for OM75S into a waveguide WR430



The flange mates Japanese standard BRJ-2

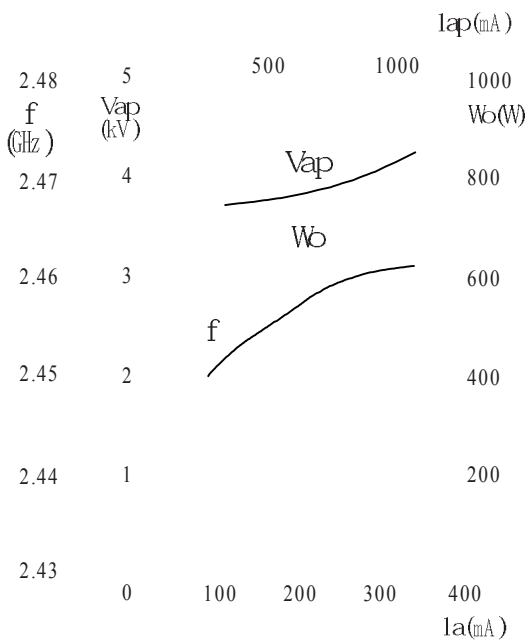


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7. RIEKE DIAGRAM IN WAVEGUIDE WR430

Power Supply : half-wave doubler L.C. type
 Filament Voltage 3.3 V
 Average Anode Current..... 300 mA
 Peak Anode Voltage 4.1 kV
 Frequency at matched load 2465MHz
 d : distance of V.S.W.R. -minimum from
 reference plane towards load
 Diagram measured under cold condition

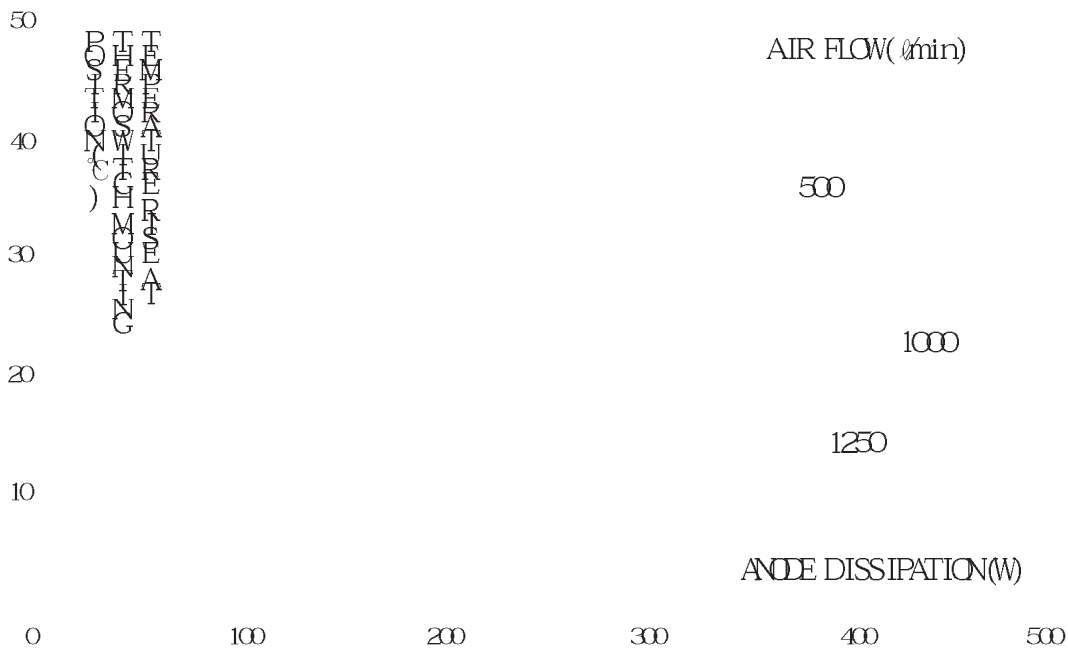
8. PERFORMANCE OF OM75S MAGNETRON



- Power Supply : single phase half-wave doubler
- Filament Voltage 3.3 V
- Load V.S.W.R. 1.1 maximum
- measured within 15sec. after applying voltage

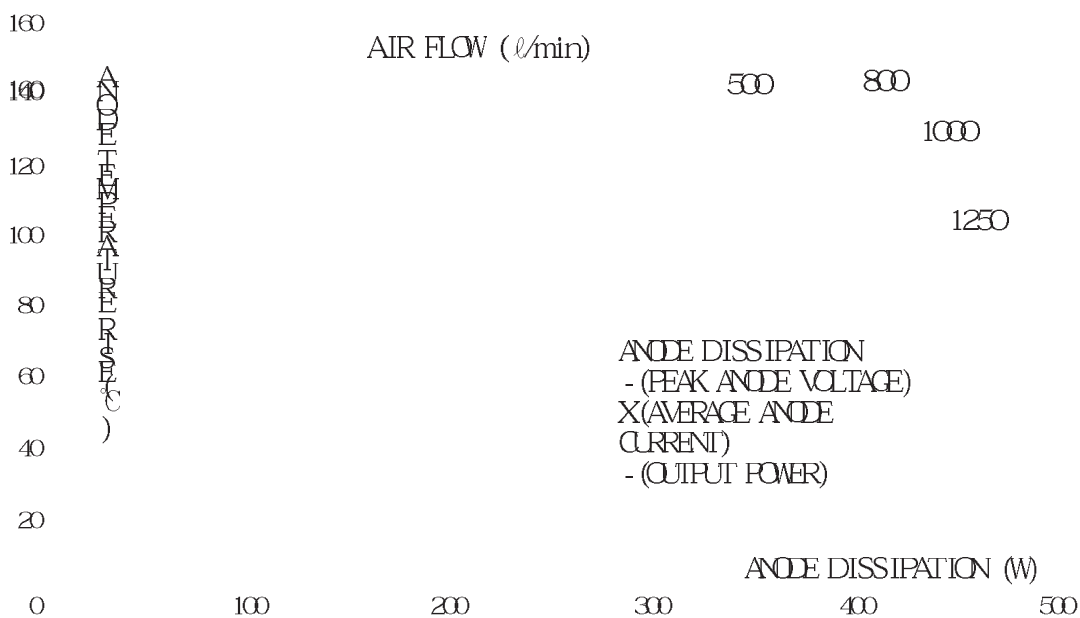
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9. ANODE DISSIPATION vs. TEMPERATURE RISE of THERMOSWITCH MOUNTING POSITION



[Increase in temperature of thermoswitch mounting position above inlet air temperature T as a function of anode dissipation W]

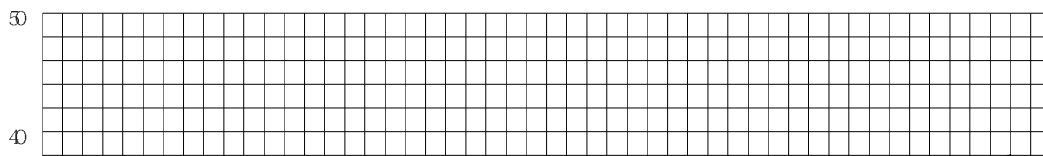
10. ANODE DISSIPATION vs. ANODE TEMPERATURE.



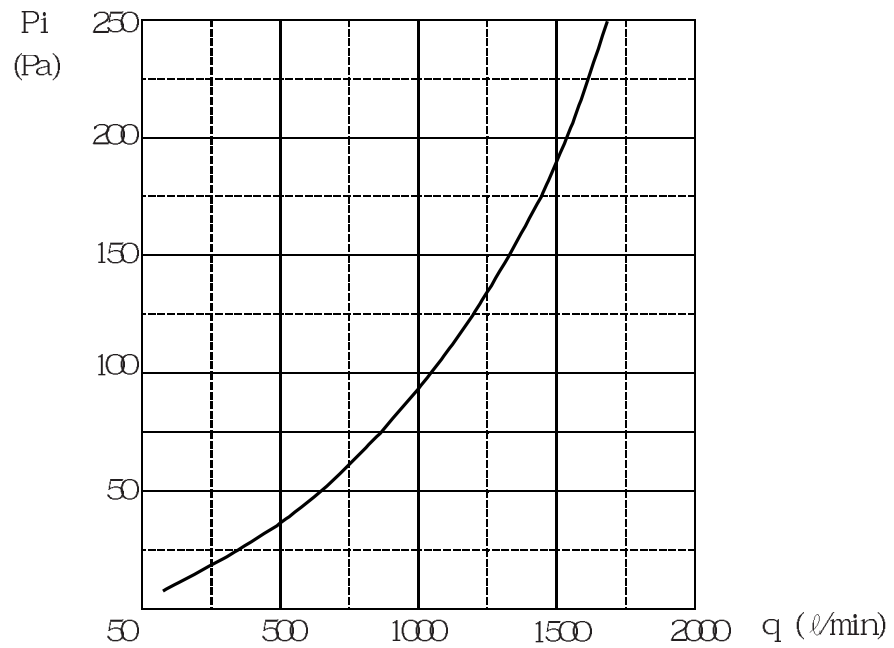
(Increase of anode temperature above inlet air temperature T as a function of anode dissipation W)

Anode dissipation = (peak anode voltage) x (average anode current) - (output power)

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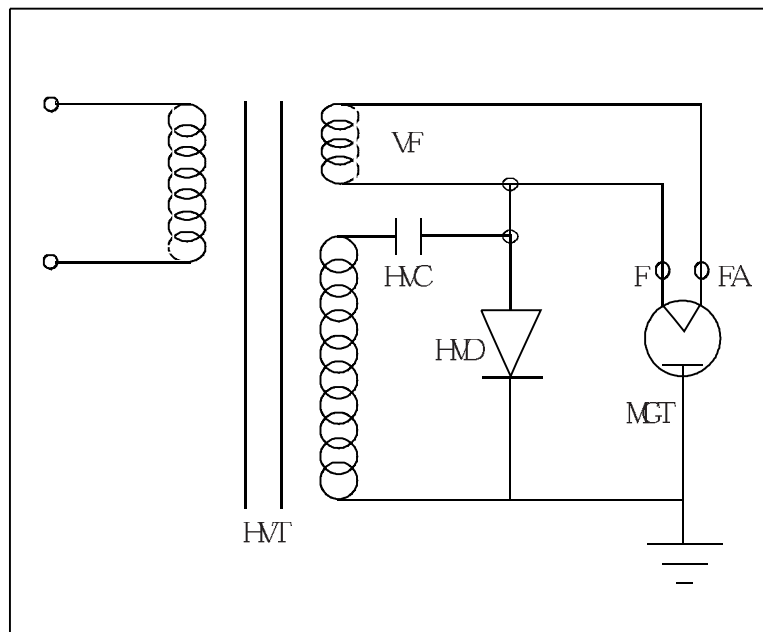


11. PRESSURE DROP vs. AIR FLOW



Pressure Drop P_i , across radiator as a function of air flow, q .

12. POWER SUPPLY CIRCUITS



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